



可控硅光耦

Photo Triac

**QXx223**

**(Rev.E)**

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## 概述 Description

QXx223 系列器件系由一个 GaAs 红外发光二极管，一个单晶硅芯片的随机相位光电双向晶闸管和一个主输出双向可控硅元件组成的光电耦合器。它们设计用于电子控制和负载之间的接口，用来控制 115 到 240VAC 之间的操作。

The QXx223 series of devices are each consist of a GaAs infrared emitting diode optically coupled to a monolithic silicon zero cross photo triac and a main output triac. They are designed for interfacing between electronic controls and loads to control inductive for 115 to 240 VAC operations.

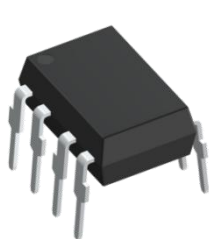
## 特性 Features

- 峰值击穿电压：600V  
Peak breakdown voltage: 600V
- 多种负载电流选择:0.3 A, 0.6A, 0.9A, 1.2A  
Multiple load current options:0.3 A, 0.6A, 0.9A, 1.2A
- 输入-输出隔离电压 ( $V_{ISO}=5000$  Vrms )  
High isolation voltage between input and output( $V_{ISO}=5000$  Vrms )
- 工作温度：-40°C~85°C  
Operating Temperature: -40°C~85°C
- 符合加强绝缘标准  
Meet reinforced insulation standards
- 符合安规标准：UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5) , CQC11-471543-2022  
Safety standard approval: UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5) , CQC11-471543-2022

## 应用 Applications

- 开关电源，智能电表  
Switching power supply, intelligent meter
- 工业控制，测量仪器  
Industrial control, measuring instruments
- 办公设备，比如复印机  
Office equipment such as copiers
- 家用电器，比如空调、风扇、热水器等  
Household appliances: such as air conditioners, fans, water heaters, etc.

## 封装和原理图 Package and Schematic Diagram



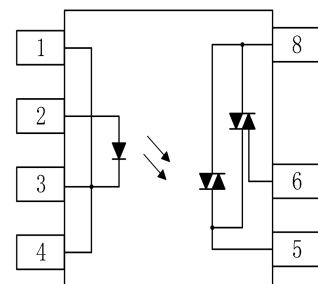
DIP7



DIP7-M



SMD7



Pin Configuration

1. Cathode
2. Anode
3. Cathode
4. Cathode
5. Gate
6. Output
8. Output


**产品型号命名规则 Order Code**

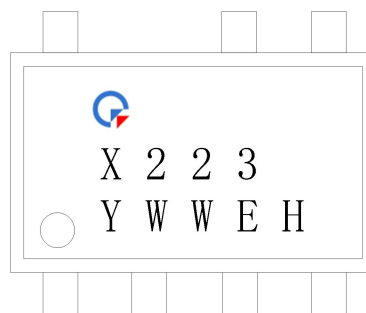
**QX X223 - UN Y - W V (ZZ)**

①            ②            ③    ④            ⑤            ⑥            ⑦

- ① 公司代码 Company Code (QX: 群芯 Qunxin)
- ② 产品系列 Product Series (X223:0223, 1223, 2223, 3223)
- ③ 框架类型 Lead Frame (Cu: 铜框架 Copper)
- ④ 树脂类型 Epoxy Type (H: 无卤 Halogen-free)
- ⑤ 封装形式 Package (D: DIP, M:DIP-M, S: SMD)
- ⑥ 产品版本 Product Versions: E
- ⑦ 内部补充代码 Internal Supplementary Code (数字或者空白 Number or None)

**印字信息 Marking Information**

- 印字中“”为群芯品牌 LOGO  
“”denotes LOGO
- 印字中的“X”代表  $I_{T(RMS)}$  分档: 0、1、2、3  
“X”denotes the  $I_{T(RMS)}$  digissr: 0、1、2、3
- 印字中“Y”代表年份; A(2018),B(2019),C(2020).....  
“Y”denotes YEAR: A(2018), B(2019), C(2020).....
- 印字中“WW”代表周号  
“WW”denotes Week’s number
- 印字中“E”代表产品版本号  
“E”denotes product versions
- 印字中的“H”代表无卤  
“H”denotes Halogen-free



**绝缘和安规信息 Insulation and Safety related specifications**

项目 Item	符号 Symbol	数值 Value	单位 Unit	备注 Remark
爬电距离 Creepage Distance	L	> 7.0	mm	从输入端到输出端，沿本体最短距离路径 Measured from input terminals to output terminals, shortest distance path along body
电气间隙 Clearance Distance	L	> 7.0	mm	从输入端到输出端，通过空气的最短距离 Measured from input terminals to output terminals, shortest distance through air
绝缘距离 Insulation Thickness	DTI	> 0.4	mm	发射器和探测器之间的绝缘厚度 Insulation thickness between emitter and detector
峰值隔离电压 Peak Isolation Voltage	$V_{IORM}$	1500	$V_{peak}$	DIN/EN/DIN EN60747-5-5
瞬态隔离电压 Transient Isolation Voltage	$V_{IOTM}$	7000	$V_{peak}$	DIN/EN/DIN EN60747-5-5
隔离电压 Isolation Voltage	$V_{iso}$	> 5000	$V_{rms}$	For 1 min

**极限参数 Absolute Maximum Ratings (Ta=25°C)**

参数 Parameter		符号 Symbol	额定值 Rated	单位 Unit
发射端 Input	正向电流 Forward Current	$I_F$	60	mA
	反向电压 Backward Voltage	$V_R$	6	V
	峰值正向电流 <sup>①</sup> Peak Forward Current	$I_{FP}$	1	A
接收端 output	断态输出端电压 Repetitive peak OFF-state Voltage	$V_{DRM}$	600	V
	通态电流(均方值) <sup>②</sup> ON-state RMS current	QX0223	0.3	A
		QX1223	0.6	
		QX2223	0.9	
		QX3223	1.2	
	通态浪涌电流 Non-repetitive surge current	QX0223	3	A
		QX1223	6	
QX2223		9		
QX3223		12		
隔离电压 Isolation Voltage	$V_{iso}$	5000	$V_{rms}$	
工作温度 Operating Temperature	$T_{opr}$	-40 ~ 85	°C	
存储温度 Storage Temperature	$T_{stg}$	-40 ~ 125	°C	
焊接温度 Soldering Temperature	$T_{sol}$	260	°C	

注释 Notes:

① F = 100Hz, 占空比 0.1%  
f = 60Hz, one cycle.

② F = 60Hz, 1周期  
f = 100Hz, Duty Cycle = 0.1%

**产品特性参数 Electro-optical Characteristics (Ta=25°C)**

参数 Parameter		符号 Symbol	条件 Condition	最小 Min.	典型 Typ.	最大 Max.	单位 Unit
发射端 Input	正向电压 Forward Voltage	$V_F$	$I_F=20\text{mA}$	-	1.23	1.4	V
	反向电流 Back current	$I_R$	$V_R = 6\text{V}$	-	-	10	$\mu\text{A}$
接收端 Output	断态峰值电流 Off-state peak current	$I_{\text{DRM}}$	$I_F = 0\text{mA},$ $V_{\text{DRM}} = 600\text{V}$	-	-	100	$\mu\text{A}$
	通态峰值电压 On-state peak voltage	$V_{\text{TM}}$	$I_F=10\text{mA},$ $I_{\text{TM}}=\text{MAX.}$	-	1.33	2.5	V
	断态电压临界上升率 Critical rise rate of off-state voltage	dV/dt	$V_{\text{DRM}}=600\text{V} \times 1/\sqrt{2}$	200	-	-	V/us
传输特性 Transfer Characteristics	LED 触发电流 LED trigger current	$I_{\text{FT}}$	$V_D=6\text{V}, R_L = 100\Omega$	-	2.9	10	mA
	维持电流 Maintain current	$I_H$	-	-	-	25	mA
	开启时间 Start time	$T_{\text{on}}$	$I_F = 20\text{mA}, V_D = 6\text{V},$ $R_L = 100\Omega$	-	-	100	$\mu\text{s}$
	隔离电阻 Isolation Resistance	$R_{\text{I-O}}$	$V_{\text{I-O}}=500\text{V DC},$ 40 to 60%RH	-	$5 \times 10^{11}$	-	$\Omega$

**典型光电特性曲线 Typical Electro-Optical Characteristics Curves**

图 1 通态电流 vs 环境温度

Fig.1 ON-state RMS current vs Ambient temperature

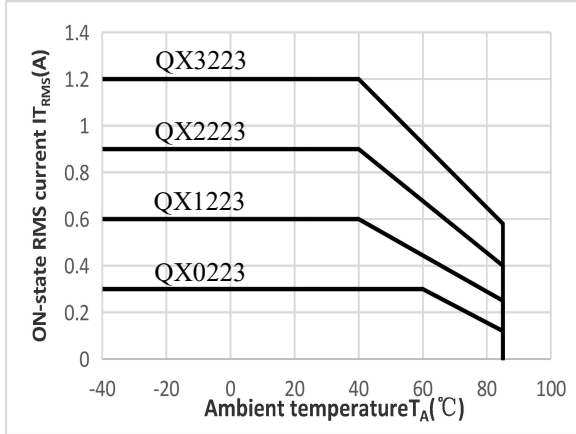


图 2 通态电压 vs 环境温度

Fig.2 On voltage vs Ambient temperature

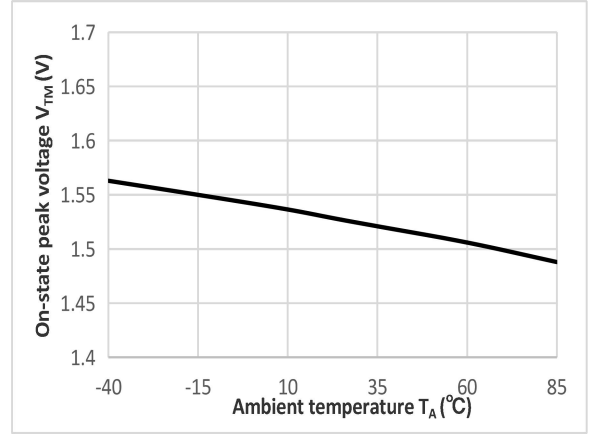


图 3 LED 触发电流 vs 环境温度

Fig.3 LED trigger current vs Ambient temperature

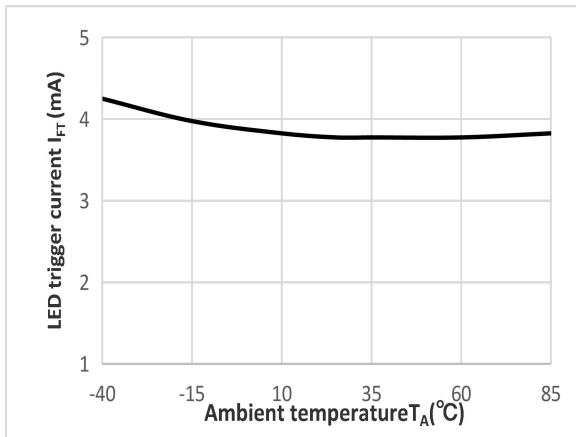


图 4 正向压降 vs 环境温度

Fig.4 Forward Voltage vs Ambient temperature

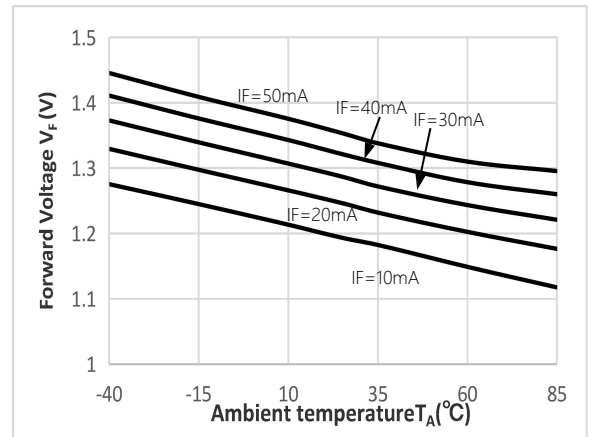


图 5 断态漏电流 vs 断态电压

Fig.5 Off-state current vs OFF-state Voltage

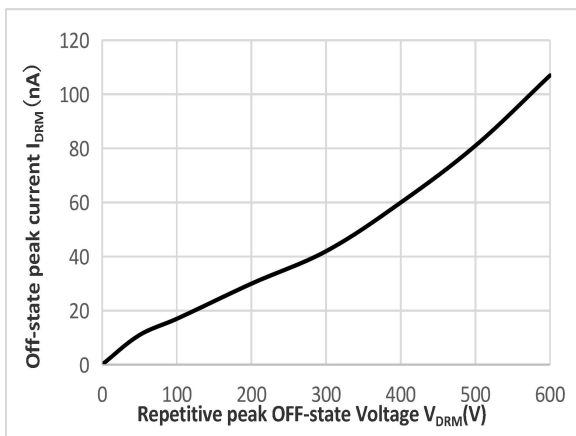


图 6 维持电流 vs 环境温度

Fig.6 Maintain current vs Ambient temperature

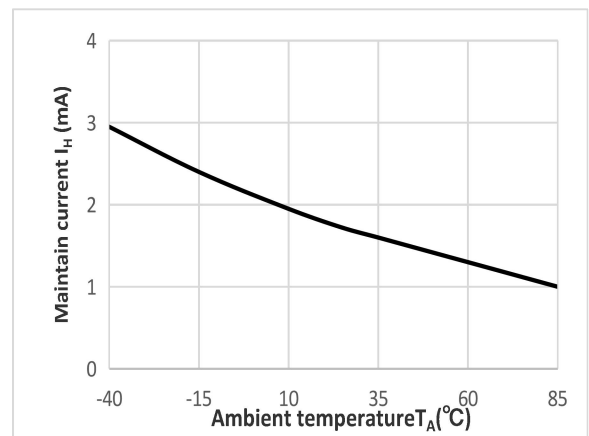
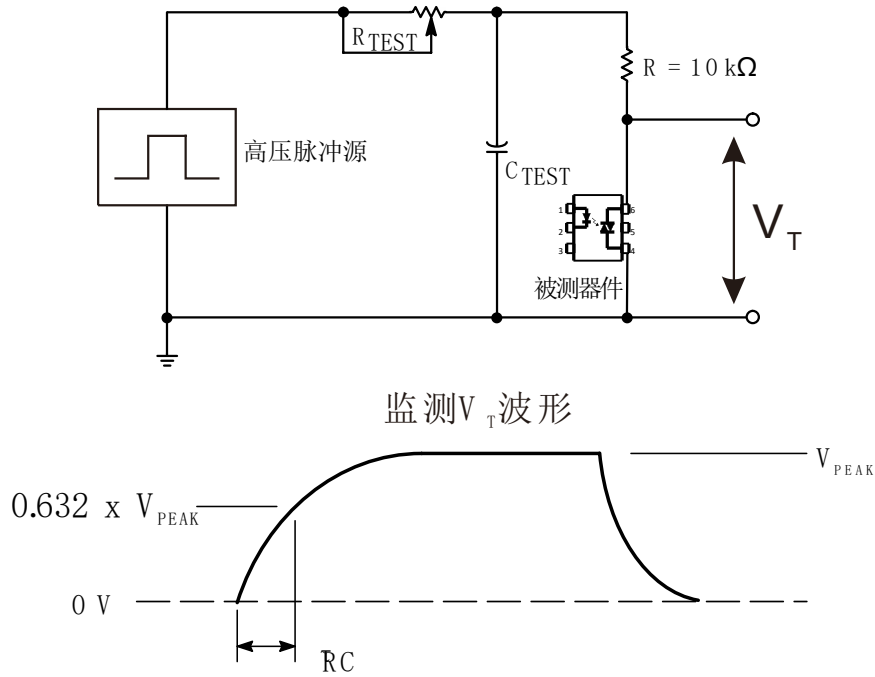


Fig.7 静态 dv/dt 测试电路和波形 Static dv/dt test circuit and waveform



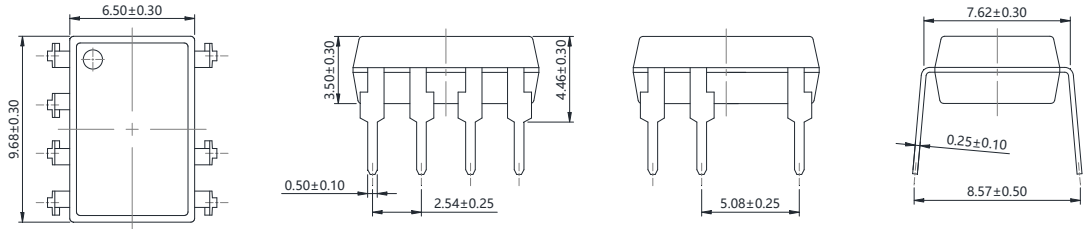
通过 RC 电路施加于被测器件的输出端的高电压脉冲设置到所需的  $V_{PEAK}$  值上。LED 电流无需加上。波形  $V_T$  使用 X100 探头监测。通过调节  $R_{TEST}$  值,  $dv/dt$  (斜度) 增加, 直到被测器件观察到被触发 (波形崩溃)。  $dv/dt$  然后下降, 直到被测器件停止被触发。此时, 记录  $\tau_{RC}$  值并可计算  $dv/dt$  了。

The high voltage pulse applied to the output end of the device under test through the RC circuit is set to the desired  $V_{PEAK}$  value. LED current does not need to be added. Waveform  $V_T$  is monitored with X100 probe. By adjusting the  $R_{TEST}$  value,  $dv/dt$  (slope) increases until the device under test is observed to be triggered (waveform collapse).  $Dv/dt$  then drops until the device under test stops being triggered. At this time,  $dv/dt$  can be calculated by recording the value of  $\tau_{RC}$ .

$$dv/dt = \frac{0.632 \times V_{PEAK}}{\tau_{RC}}$$

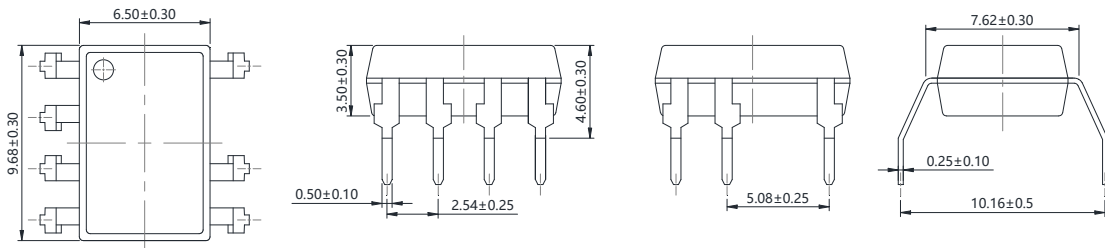
**外形尺寸 Outline Dimensions**

DIP7



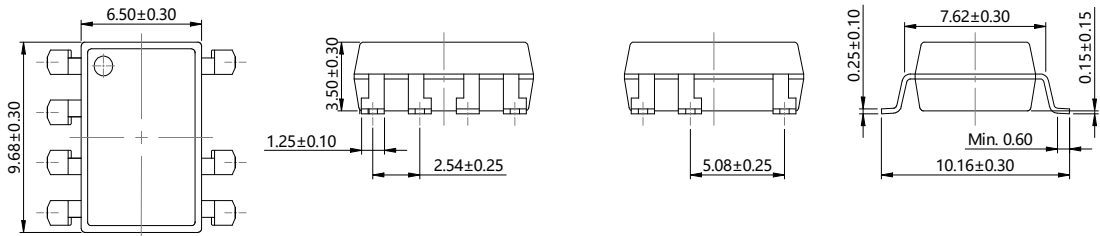
单位 Unit: mm

DIP7-M



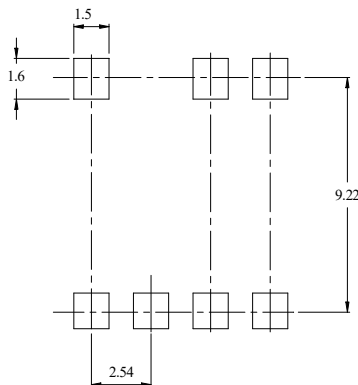
单位 Unit: mm

SMD7



单位 Unit: mm

**建议焊盘布局 Recommended Pad Layout**

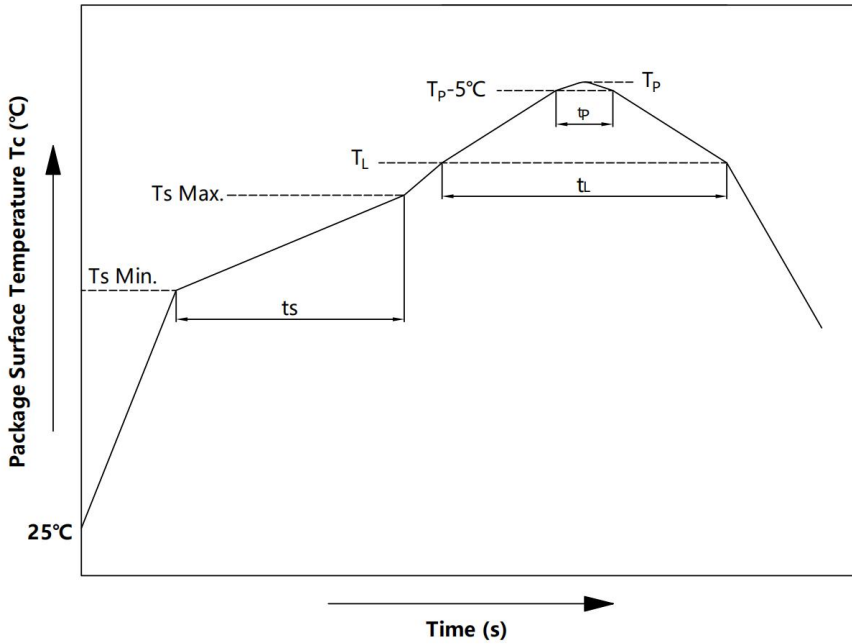


单位 Unit: mm

注：上图为产品正视图。

Note: The picture above is the front view of the product.

**回流焊温度曲线图 Solder Reflow Profile**



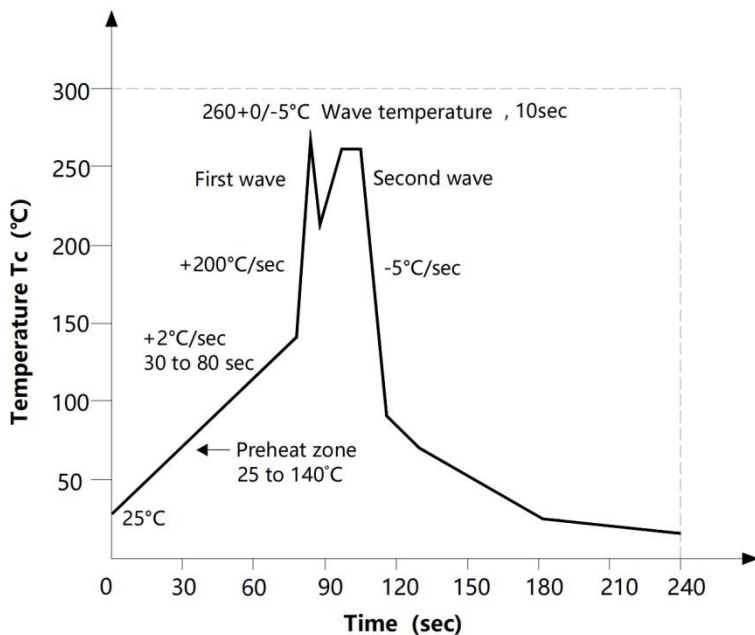
项目 Item	符号 Symbol	最小值 Min.	最大值 Max.	单位 Unit
预热温度 Preheat Temperature	$T_s$	150	200	$^\circ\text{C}$
预热时间 Preheat Time	$t_s$	60	120	s
升温速率 Ramp-Up Rate ( $T_L$ to $T_P$ )	-	-	3	$^\circ\text{C}/\text{s}$
液相线温度 Liquidus Temperature	$T_L$	217		$^\circ\text{C}$
时间高于 $T_L$ Time Above $T_L$	$t_L$	60	150	s
峰值温度 Peak Temperature	$T_P$	-	260	$^\circ\text{C}$
$T_c$ 在 $(T_P-5)$ 和 $T_P$ 之间的时间 Time During Which $T_c$ Is Between $(T_P-5)$ and $T_P$	$t_p$	-	30	s
降温速率 Ramp-down Rate ( $T_P$ to $T_L$ )	-	-	6	$^\circ\text{C}/\text{s}$

注 Note:

建议在所示的温度和时间条件下进行回流焊，最多不能超过三次；

Reflow soldering is recommended at the temperatures and times shown, no more than three times;

### 波峰焊温度曲线图 Wave Soldering Profile



### 手工烙铁焊接 Soldering with hand soldering iron

- A. 手工烙铁焊仅用于产品返修或样品测试;  
Hand soldering iron is only used for product rework or sample testing;
- B. 手工烙铁焊要求: 温度  $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$ , 时间  $\leq 3\text{s}$ 。  
Hand soldering iron requirements: Temperature:  $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$ , within 3s

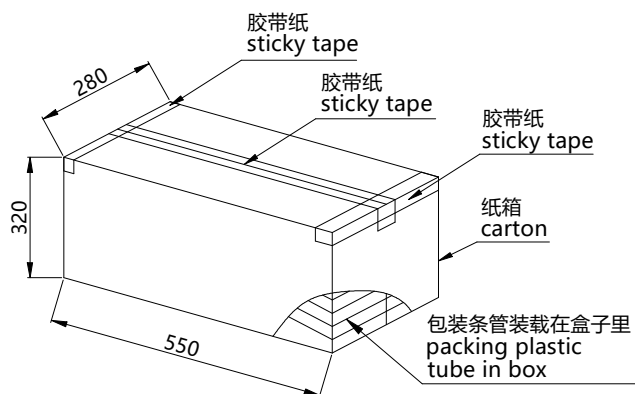
**包装 Packing**

■ 汇总表 Summary table

封装形式	包装方式	盘数量	盒数量	箱数量	静电袋规格	盒规格	箱(双瓦楞)规格	备注
DIP7	管装 (500*12*11mm)	45 只/管	50 管/盒	10 盒/箱	不适用	525*130*57mm	550*280*320mm	每管使用蓝白胶塞, 方向须一致
DIP7-M	管装 (500*12*11mm)	45 只/管	45 管/盒	10 盒/箱	不适用	525*130*57mm	550*280*320mm	每管使用蓝白胶塞, 方向须一致
SMD7	卷盘 (φ330mm 蓝盘)	1000/盘	2 盘/盒	10 盒/箱	450*390*0.1mm	353*340*60mm	650*375*365mm	首端空 50 个空格 末端空 100 个空格
Package Type	Packing Form	Quantity per Reel	Quantity per Box	Quantity per Carton	Antistatic Bag Specification	Box Specification	Carton Specification	Note
DIP7	Tube (500*12*11mm)	45 pcs /Tube	50 Tubes /box	10 boxes /ctn	Not applicable	525*130*57mm	550*280*320mm	Use blue and white rubber stoppers for each tube, with the same direction
DIP7-M	Tube (500*12*11mm)	45 pcs /Tube	45 Tubes /box	10 boxes /ctn	Not applicable	525*130*57mm	550*280*320mm	Use blue and white rubber stoppers for each tube, with the same direction
SMD7	Reel (φ330mm Blue)	1k pcs/reel	2 reels /box	10 boxes /ctn	450*390*0.1mm	353*340*60mm	650*375*365mm	Leave 50 Spaces at the beginning and 100 Spaces at the end

■ 管条包装 Tape & Tube

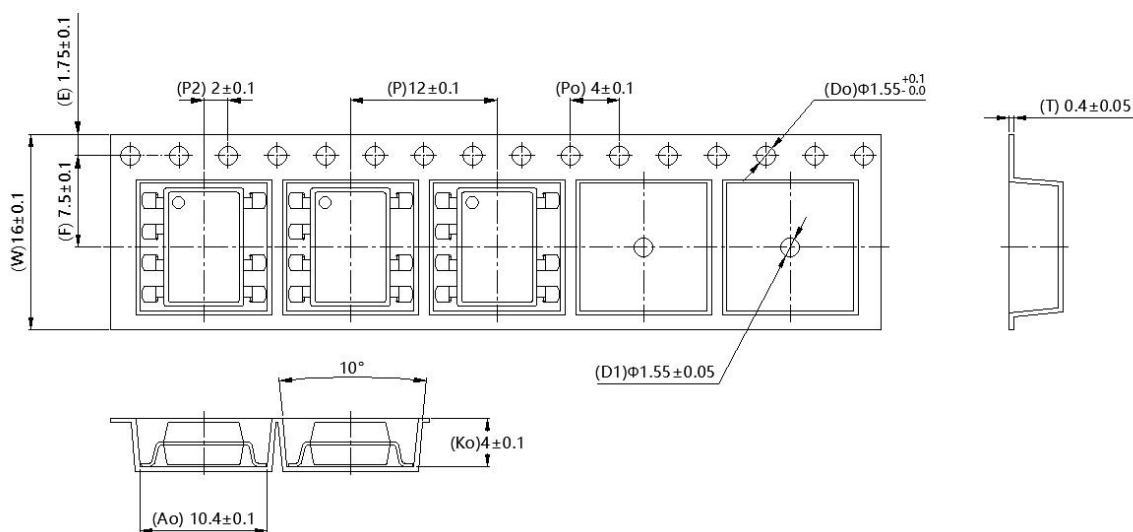
- 1) 每管数量: 45 只。  
Qty/Tube: 45 pcs.
- 2) 每箱数量 DIP7/DIP7-M: 22500/20250 只。  
Qty/ctn DIP7/DIP7-M: 22500/20250 pcs.
- 3) 内包装 DIP7/DIP7-M: 每盒 50/45 管。  
Inner packing DIP7/DIP7-M: 50/45 Tube/box.
- 4) 示意图 Schematic:



单位 Unit: mm

■ 编带包装 Tape & Reel

- 1) 每卷数量: 1000 只。  
Qty/reel: 1000 pcs.
- 2) 每箱数量: 20000 只。  
Qty/ctn: 20000 pcs.
- 3) 内包装: 每盒 2 盘。  
Inner packing: 2 reels/box.
- 4) 示意图 Schematic:



单位 Unit: mm

**注意 Attention**

- 群芯持续不断改进质量、可靠性、功能或设计，保留此产品更改的权利恕不另行通知。  
QUNXIN continuously improve quality, reliability, function and design. We reserve the right to change this product without prior notice.
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Please use in accordance with the product specification. QUNXIN is not responsible for the quality problems caused by non-compliance with the product specifications.
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